Supplementary Information (SI) for Nanoscale Advances. This journal is © The Royal Society of Chemistry 2025

## **Supplementary Information**

## Structurally Engineered Heat Loss Suppression in Nanogap-Aligned Nanowires for Power Efficient Heating

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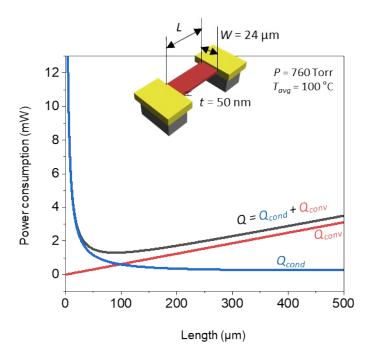
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**Figure S1.** The analytic calculations of power consumption required to reach an average beam temperature of 100 °C at 760 torr in a 50 nm-thick, 24  $\mu$ m-wide Pt thin film as a function of length (up to 500  $\mu$ m), along with the trends in conduction and convection.

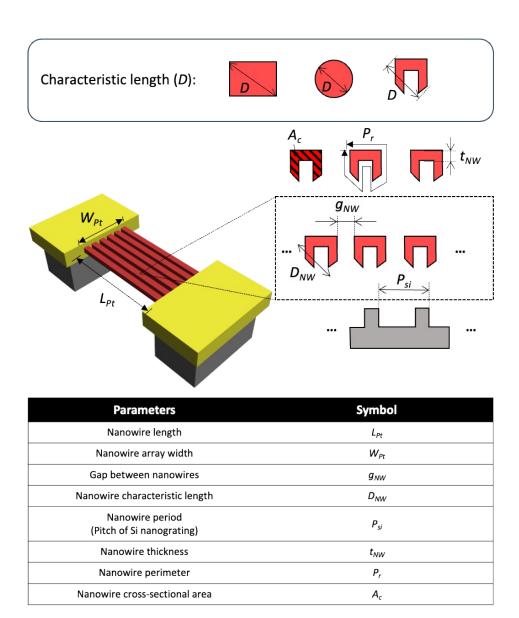
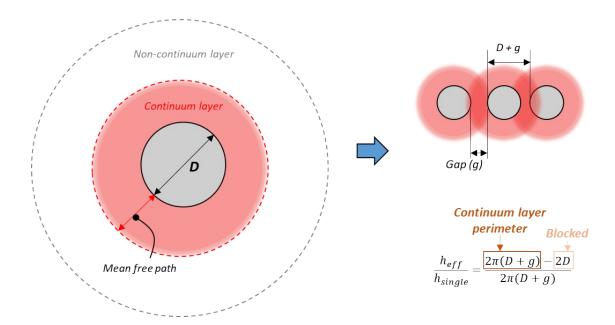
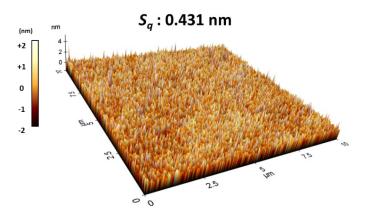


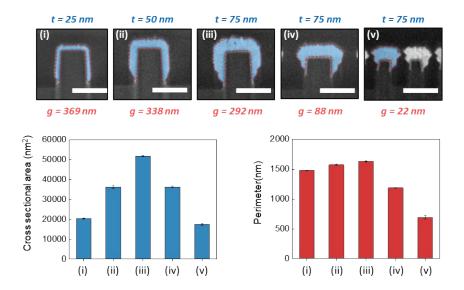
Figure S2. Geometrical parameters and symbols in the fabricated nanowire array for the calculation.



**Figure S3.** Schematic of the two-layer model showing the continuum layer and the change in the effective convective heat transfer coefficient when materials are close enough for their continuum layers to overlap, blocking molecular interactions.



**Figure S4.** Measured surface roughness using atomic force microscopy for a 30 nm Pt film with a 10 nm Cr adhesion layer at the same deposition and annealing condition with other Pt samples.



**Figure S5.** The cross-sectional area and perimeter of the fabricated C-shaped nanowires measured from the respective SEM images.

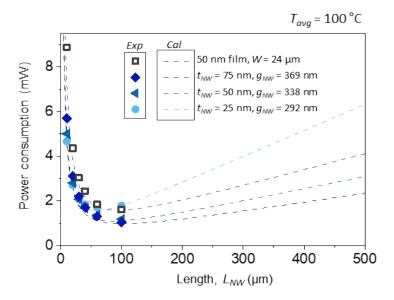


Figure S6. Power consumption with respect to length, up to 500  $\mu m$ , as an extended plot of Figure 4d.

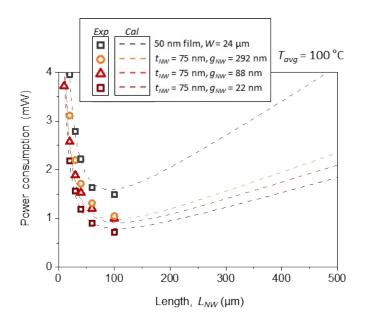


Figure S7. Power consumption with respect to length, up to 500  $\mu m$ , as an extended plot of Figure 5c.